

DECLARATION FOR NON-PROVISIONAL PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below at 201 et seq. beneath my name.

I believe I am the original, first and sole inventor if only one name is listed at 201 below, or an original, first and joint inventor if plural names are listed at 201 et seq. below, of the subject matter which is claimed and for which a patent is sought on the invention entitled

**A METHOD OF PRODUCING A SEMICONDUCTOR STRUCTURE HAVING AT LEAST ONE
SUPPORT SUBSTRATE AND AN ULTRATHIN LAYER**

- ☐ is attached hereto.
☒ which is identified by docket No. **4717-11900**
☐ which was filed on _____ as Application No. _____.

I hereby state that I have reviewed and understand the contents of the above identified application, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

EARLIEST FOREIGN APPLICATION(S), IF ANY, FILED PRIOR TO THE FILING DATE OF THE APPLICATION			
APPLICATION NUMBER	COUNTRY	DATE OF FILING (day, month, year)	PRIORITY CLAIMED
03 06843	France	6/6/03	<input checked="" type="checkbox"/> YES <input type="checkbox"/> NO
			<input type="checkbox"/> YES <input type="checkbox"/> NO

I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below.

PROVISIONAL APPLICATION NUMBER	FILING DATE


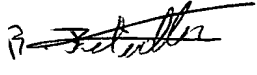

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code § 112, I acknowledge the duty to disclose information known to me which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:


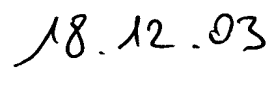
NON-PROVISIONAL APPLICATION NO.	FILING DATE	STATUS		
		PATENTED	PENDING	ABANDONED

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SEND CORRESPONDENCE TO: WINSTON & STRAWN LLP
PTO Customer No. 28765

DIRECT TELEPHONE CALLS TO
Allan A. Fanucci at 212-294-3311

201	FULL NAME OF INVENTOR	LAST NAME AULNETTE	FIRST NAME Cécile	MIDDLE NAME	
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		SIGNATURE OF INVENTOR 201 		DATE October 31st 2003	
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		SIGNATURE OF INVENTOR 202 		DATE October 31st 2003	
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		SIGNATURE OF INVENTOR 203 		DATE 31 October 2003	

2 0 4	FULL NAME OF INVENTOR	LAST NAME MORICEAU	FIRST NAME Hubert	MIDDLE NAME	
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		SIGNATURE OF INVENTOR 204 		DATE 	

DD 251300

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Cécil AULNETTE et al.

Application No.: To be assigned

Group Art Unit:

Filing Date:

Examiner:

For: A METHOD OF PRODUCING A
SEMICONDUCTOR STRUCTURE HAVING
AT LEAST ONE SUPPORT SUBSTRATE
AND AN ULTRATHIN LAYER

Attorney Docket No.: 4717-11900

**POWER OF ATTORNEY BY ASSIGNEES
AND EXCLUSION OF INVENTOR(S) UNDER 37 C.F.R. 3.71**

Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

Sir:

The undersigned assignee of the entire interest in the above-identified subject application hereby appoints Allan A. Fanucci (Reg. No. 30,256) and Daniel J. Hulseberg (Reg. No. 36,554) of WINSTON & STRAWN (Customer No. 28765) to prosecute this application and to transact all business in the United States Patent and Trademark Office connected therewith.

Please direct all correspondence for this application to Customer No. 28765 to the attention of Allan A. Fanucci (telephone 212-294-3311, facsimile 212-294-4700).

An assignment of the entire interest in the above-identified subject application is submitted herewith for recording and a copy is attached. The undersigned has reviewed this assignment and, to the best of his knowledge, title is in the assignee seeking to take action in this application and that he is empowered to act on its behalf.

ASSIGNEE: **S.O.I. TEC SILICON ON INSULATOR TECHNOLOGIES S.A.**

Signature:

Date of Signature:

Typed Name:

Position/Title:

Address:



October 30th 2003

Emmanuel HUYGHE

IP Manager

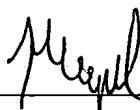
Parc Technologique des Fontaines, F-38190 Bernin,

France

ASSIGNEE:

COMMISSARIAT À L'ENERGIE ATOMIQUE (CEA),

Signature:



R. NAGEL
Chef de Service

Date of Signature:

22/01/2004

Typed Name:

RICHARD NAGEL

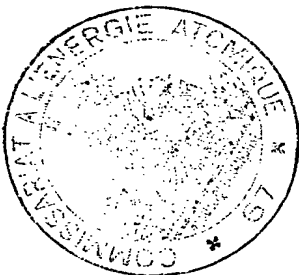
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